

RF-SM-1077B2 Ultra-Low-Power 433 MHz & 470 MHz Wireless Module

Version 1.0

Shenzhen RF-star Technology Co., Ltd.

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TI CC13XX Sub-1 GHz Module List

Chipset	Core	FLASH (KB)	RAM (KB)	Model	Antenna	Freq. (MHz)	Dimension (mm)	TX Power (dBm)	Range (M)	Photo	
CC1310	M3	128	8	RF-SM-1077B1	IPEX	868 915	18 × 26	14	2500	2 €	
F128RGZ	IVIS	120	0	RF-SM-1077B2	IPEX	433 470	18 × 26	15	2500	8 8 8 8 8 8 8 8 8 8	
				RF-SM-1044B1	РСВ	868 915	14 × 22	14	2500		
CC1310 F128RSM	M3	128	8	RF-SM-1044B2	РСВ	868 915	9 × 12.5	14	2500		
					RF-SM-1044B4	Half- hole	868 915	14 × 22	14	2500	87-54-104-84
								5	BLE: 500		
CC1352R	M4F	352	80	80 RF-TI1352B1 IPEX 868 915 16.8 × 26.5	IPEX		16.8 × 26.5	5	ZigBee: 300		
					14	868 MHz: 1500					
								20	BLE 1M: 350		
CC1352P	M4F	352	80	RF-TI1352P1	Half-	868	16.4 × 25	20	BLE Long Range: 2200	330	
						hole	915		20	ZigBee: 1100	₩ :
									20	868 MHz: 2500	

Note:

- 1. The communication distance is the longest distance obtained by testing the module's maximum transmission power in an open and interference-free environment in sunny weather.
- 2. Click the picture to buy modules.



1 Device Overview

1.1 Description

RF-SM-1077B2 Sub-1 GHz module is based on TI CC1310, which combines a flexible, very low-power RF transceiver with a powerful 48 MHz ARM® Cortex®-M3 microcontroller supporting multiple physical layers and RF standards and a dedicated radio controller Cortex®-M0 handling RF protocol commands that are stored in ROM or RAM. RF-SM-1077B2 integrates a 24.0 MHz crystal, a balun, a band pass filter, an antenna matching and an IPEX antenna matching which make the module low cost, low power consumption and long wireless communication in Sub-1 GHz.

1.2 Key Features

- Microcontroller
 - Powerful ARM® Cortex®-M3 processor
 - EEMBC CoreMark® Score: 142
 - EEMBC ULPBench™ score: 158
 - Clock speed up to 48 MHz
 - 128 KB of in-system programmable flash
 - 8 KB of SRAM for Cache (or as general-purpose RAM)
- 20 KB of ultra-low-leakage SRAM
- 2-pin cJTAG and JTAG debugging
- Supports over-the-air (OTA) update
- On-Chip Internal DC/DC Converter
- Ultra-Low-Power Sensor Controller
- Can run autonomously from the rest of the
- System
- 16-bit architecture
- 2 KB of ultra-low-leakage SRAM for code and data
- RF-Section
 - Excellent receiver sensitivity: -124 dBm @ longrange mode, -110 dBm @ 50 kbps
 - Excellent selectivity (±100 kHz): 56 dB
 - Excellent blocking performance (±10 MHz): 90 dB
 - Programmable output power up to +15 dBm
 - Differential RF interface
 - Suitable for systems targeting compliance with worldwide radio frequency regulations
 - > ETSI EN 300 220, EN 303 204 (Europe)
 - > FCC CFR47 Part 15 (US)

- > ARIB STD-T108 (Japan)
- Wireless M-Bus (EN 13757-4) and IEEE[®] 802.15.4g PHY
- Peripherals
 - All digital peripheral pins can be routed to any GPIO
 - Four general-purpose timer modules (eight 16-bit or four 32-bit timers, PWM each)
 - 12-bit ADC, 200 ksamples/s, 8-channel analog MUX
 - Continuous time comparator
 - Ultra-low-power clocked comparator
 - Programmable current source
 - UART
 - 2× SSI (SPI, MICROWIRE, TI)
 - I2C, I2S
 - Real-time clock (RTC)
 - AES-128 security module
 - True random number generator (TRNG)
 - Support for eight capacitive sensing buttons
- Integrated temperature sensor
- Low Power
 - Wide supply voltage range: 1.8 V to 3.8 V
 - RX: 5.4 mA
 - TX at +10 dBm: 13.4 mA
 - Active-mode MCU 48 MHz running Coremark: 2.5 mA (51 μA/MHz)
 - Active-mode MCU: 48.5 CoreMark/mA



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- Active-mode sensor controller at 24 MHz: 0.4 mA
 + 8.2 μA/MHz
- Sensor controller, one wake-up every second performing one 12-bit ADC sampling: $0.95~\mu A$
- Standby: 0.7 μA (RTC running and RAM and CPU retention)
- Shutdown: 185 nA (wakeup on external events)

1.3 Applications

- 433-, 470-MHz ISM and SRD systems
- Low-power wireless systems with 50-kHz to 5-MHz channel spacing
- Home and building automation
- · Wireless alarm and security systems
- Industrial Monitoring and Control
- · Smart grid and automatic meter reading
- · Wireless healthcare applications
- Wireless sensor networks

- Active RFID
- IEEE 802.15.4g, IP-enabled smart objects (6LoWPAN), wireless M-Bus, KNX systems, Wi-SUN™, and proprietary systems
- Energy-harvesting applications
- Electronic shelf label (ESL)
- Long-range sensor applications
- Heat-cost allocators

1.4 Functional Block Diagram

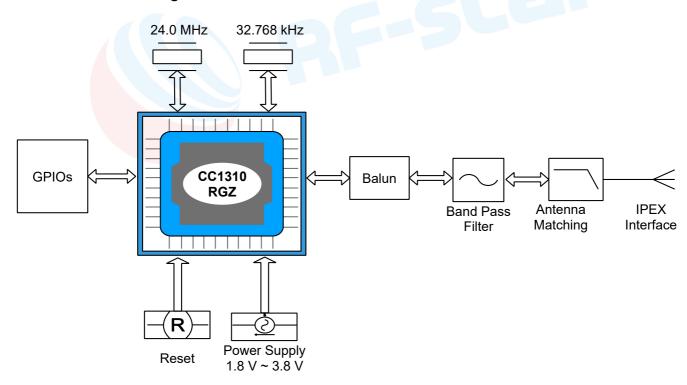


Figure 1. Functional Block Diagram of RF-SM-1077B2



1.5 Working Mode

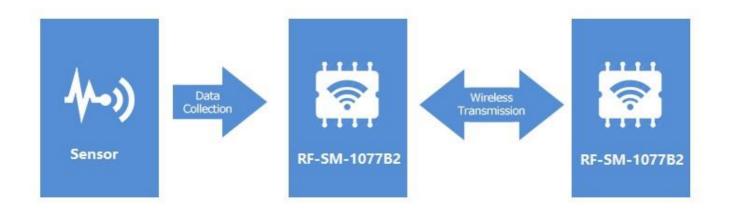


Figure 2. Working Mode of RF-SM-1077B2

1.6 Part Number Conventions

The part numbers are of the form of RF-SM-1077B2 where the fields are defined as follows:

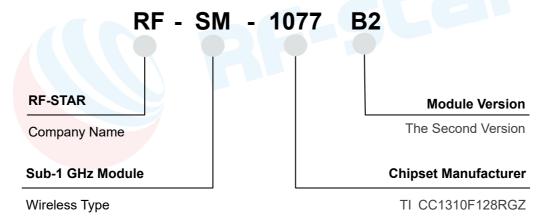


Figure 3. Part Number Conventions of RF-SM-1077B2



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2 Module Configuration and Functions

2.1 Module Parameters

Table 1. Parameters of RF-SM-1077B2

Chipset	CC1310F128RGZ
Supply Power Voltage	1.8 V ~ 3.8 V, recommended to 3.3 V
Frequency	433 MHz, 470 MHz
Maximum Transmit Power	+15.0 dBm
Receiving Sensitivity	-124.0 dBm (@long range mode)
Receiving Sensitivity	-110.0 dBm (@50 kpbs)
GPIO	30
Crystal	24 MHz, 32.768 kHz
RAM	20 KB
Flash	128 KB
Package	SMT Packaging
Frequency Error	±20 kHz
Dimension	26.0 mm x 18.0 mm x (2.3 ± 0.1) mm
Type of Anten <mark>na</mark>	IPEX interface
Operating Temperature	-40 ℃ ~ +85 ℃
Storage Temperature	-40 ℃ ~ +125 ℃



2.2 Module Pin Diagram

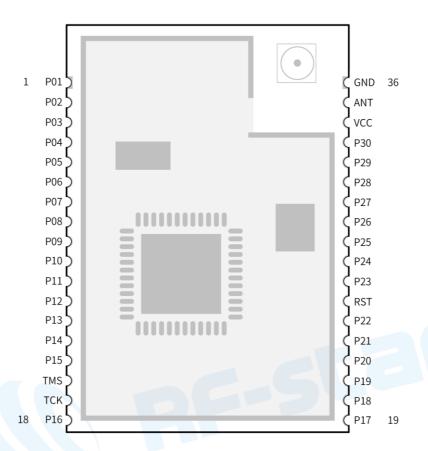


Figure 4. Pin Diagram of RF-SM-1077B2

2.3 Pin Functions

Table 2. Pin Functions of RF-SM-1077B2

Pin	Name	Chip Pin	Pin Type	Description
1	P01	DIO_1	Digital I/O	GPIO, Sensor Controller
2	P02	DIO_2	Digital I/O	GPIO, Sensor Controller
3	P03	DIO_3	Digital I/O	GPIO, Sensor Controller
4	P04	DIO_4	Digital I/O	GPIO, Sensor Controller
5	P05	DIO_5	Digital I/O	GPIO, Sensor Controller
6	P06	DIO_6	Digital I/O	GPIO, Sensor Controller
7	P07	DIO_7	Digital I/O	GPIO, Sensor Controller
8	P08	DIO_8	Digital I/O	GPIO
9	P09	DIO_9	Digital I/O	GPIO



	I			
10	P10	DIO_10	Digital I/O	GPIO
11	P11	DIO_11	Digital I/O	GPIO
12	P12	DIO_12	Digital I/O	GPIO
13	P13	DIO_13	Digital I/O	GPIO
14	P14	DIO_14	Digital I/O	GPIO
15	P15	DIO_15	Digital I/O	GPIO
16	TMS	JTAG_TMSC	-	JTAG TMS
17	TCK	JTAG_TCKC	-	JTAG TCK
18	P16	DIO_16	Digital I/O	JTAG TDO
19	P17	DIO_17	Digital I/O	JTAG TDI
20	P18	DIO_18	Digital I/O	GPIO
21	P19	DIO_19	Digital I/O	GPIO
22	P20	DIO_20	Digital I/O	GPIO
23	P21	DIO_21	Digital I/O	GPIO
24	P22	DIO_22	Digital I/O	GPIO
25	RESET	RESET_N	-	Reset, active low. No internal pullup.
26	P23/ADC0	DIO_23	Digital or analog I/O	GPIO, Sensor Controller, analog
27	P24/ADC1	DIO_24	Digital or analog I/O	GPIO, Sensor Controller, analog
28	P25	DIO_25	Digital or analog I/O	GPIO, Sensor Controller, analog
29	P26	DIO_26	Digital or analog I/O	GPIO, Sensor Controller, analog
30	P27	DIO_27	Digital or analog I/O	GPIO, Sensor Controller, analog
31	P28	DIO_28	Digital or analog I/O	GPIO, Sensor Controller, analog
32	P29	DIO_29	Digital or analog I/O	GPIO, Sensor Controller, analog
33	P30	DIO_30	Digital or analog I/O	GPIO, Sensor Controller, analog
34	VCC	VCC	-	1.8 V ~ 3.8 V, recommended to 3.3 V
35	ANT	-	-	External antenna pin
36	GND	GND	-	Ground



3 Specifications

3.1 Recommended Operating Conditions

Functional operation does not guarantee performance beyond the limits of the conditional parameter values in the table below. Long-term work beyond this limit will affect the reliability of the module more or less.

Table 3. Recommended Operating Conditions of RF-SM-1077B2

Items	Condition	Min.	Тур.	Max.	Unit
Operating Supply Voltage	Battery Mode	1.8	3.3	3.8	V
Operating Temperature	/	-40	+25	+85	$^{\circ}$ C
Environmental Hot Pendulum	1	-20		+20	°C/min

3.2 Handling Ratings

Table 4. Handling Ratings of RF-SM-1077B2

Items	Condition	Min.	Тур.	Max.	Unit
Storage Temperature	Tstg	-40	+25	+125	$^{\circ}$
Human Body Model	НВМ		±3000		V
Moisture Sensitivity Level			2		
Charged Device Model			±500		V

3.3 Power Consumption

3.3.1 Current Consumption

The current consumption characteristics of this module are categorized into different running modes. The overall product level current consumption is averaged over time on different power modes the device runs on. The peripheral circuitry's current consumption also adds in.

Table 5. Current Consumption of RF-SM-1077B2

Parameter		Test Conditions	Min.	Тур.	Max	Unit	
Core	Core Current Consumption						
	Core current	Reset. RESET_N pin asserted or VDDS below power-on-reset (POR) threshold		100		nA	
Icore	consumption	Shutdown. No clocks running, no retention		185		nA	
		Standby. With RTC, CPU, RAM and (partial)		0.7		μA	



		register retention. RCOSC_LF		
		Standby. With RTC, CPU, RAM and (partial) register retention. XOSC_LF	0.8	μА
		Idle. Supply Systems and RAM powered.	570	μA
		Active. MCU running CoreMark at 48 MHz	1.2 mA + 25.5 μA/MHz	
		Active. MCU running CoreMark at 48 MHz	2.5	mA
		Active. MCU running CoreMark at 24 MHz	1.9	mA
		Radio RX, 868 MHz	5.5	mA
		Radio TX, 10-dBm output power, (G)FSK, 868 MHz	13.4	mA
		Radio TX, OOK modulation, 10-dBm output power, AVG	11.2	mA
		Radio TX, boost mode (VDDR = 1.95 V), 14-dBm output power, (G)FSK, 868 MHz	23.5	mA
		Radio TX, OOK modulation, boost mode (VDDR = 1.95 V), 14 dBm, AVG	14.8	mA
		Radio TX, boost mode (VDDR = 1.95 V), 15-dBm output power, (G)FSK, measured on RF-SM-1077B2, 433.92 MHz	25.1	mA
		Radio TX, 10-dBm output power, measured on RF-SM-1077B2, 433.92 MHz	13.2	mA
Peripl	neral Current C	consumption (Adds to core current l _{core} for each po	eripheral unit activated) (1) (2) (3)	
	Peripheral power domain	Delta current with domain enabled	20	μА
I _{peri}	Serial power domain	Delta current with domain enabled	13	μА
	RF Core	Delta current with power domain enabled, clock enabled, RF core idle	237	μA
	μDMA	Delta current with clock enabled, module idle	130	μA



Timers	Delta current with clock enabled, module idle	113	μA
I ² C	Delta current with clock enabled, module idle	12	μA
I ² S	Delta current with clock enabled, module idle	36	μA
SSI	Delta current with clock enabled, module idle	93	μA
UART	Delta current with clock enabled, module idle	164	μA

Note:

- (1) Adds to core current I_{core} for each peripheral unit activated.
- (2) I_{peri} is not supported in standby or shutdown modes.
- (3) Measured at 3.0 V.

3.3.2 Power Consumption Test

Table 6. Power Consumption of RF-SM-1077B2

Mode	Min. Current	Max. Current	Average Current	Samples
Idle	1.29 mA	1.32 mA	1.31 mA	5000
Standby	68 nA	69.2 μΑ	980 nA	5000
Shutdown	52 nA	88 nA	79 nA	5000
RF-RX	5.2 mA	5.7 mA	5.4 mA	5000
RF-TX	-	25.2 mA (15 dBm)	-	-

Note:

Test conditions: battery power supply: 2.88 V. Test instrument: RIGOL DM3068 digital multimeter.

Data of RF-TX only provide peak value as a reference, the average power is proportional to the frequency of data transmission.



4 Application, Implementation, and Layout

4.1 Module Photos

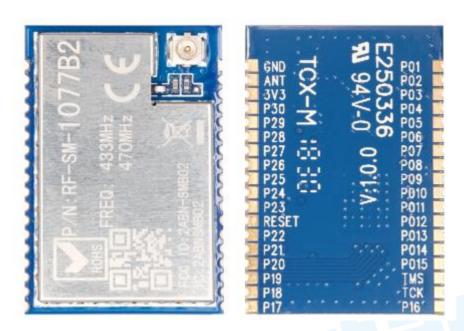


Figure 5. Photos of RF-SM-1077B2

4.2 Recommended PCB Footprint

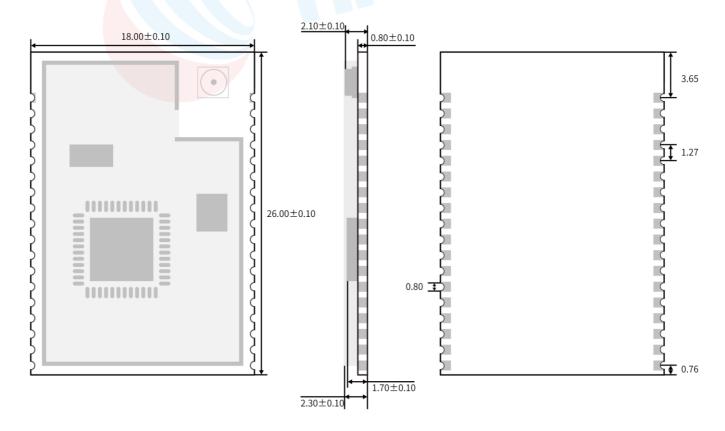


Figure 6. Recommended PCB Footprint of RF-SM-1077B2 (mm)



4.3 Antenna

RF-SM-1077B2 module is integrated the IPEX version 1 antenna seat, the specification of antenna seat is as follow:

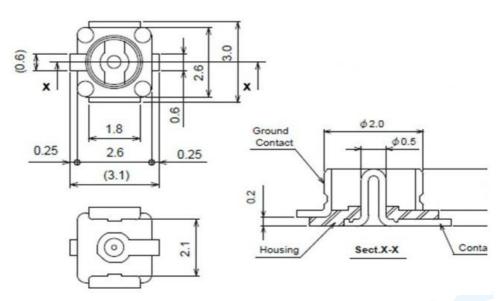


Figure 7. Specification of Antenna Seat

The specification of IPEX wire end is as follow:

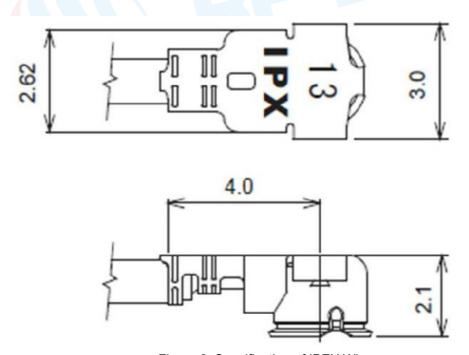


Figure 8. Specification of IPEX Wire



4.4 Schematic Diagram

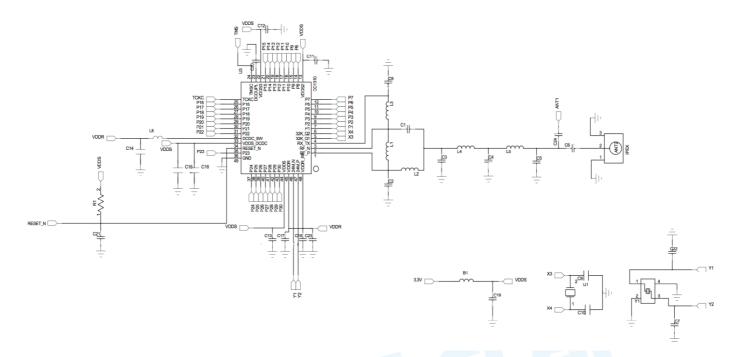


Figure 9. Schematic Diagram of RF-SM-1077B2

4.5 Basic Operation of Hardware Design

- It is recommended to offer the module with a DC stabilized power supply, a tiny power supply ripple coefficient and
 the reliable ground. Please pay attention to the correct connection between the positive and negative poles of the
 power supply. Otherwise, the reverse connection may cause permanent damage to the module;
- 2. Please ensure the supply voltage is between the recommended values. The module will be permanently damaged if the voltage exceeds the maximum value. Please ensure the stable power supply and no frequently fluctuated voltage.
- 3. When designing the power supply circuit for the module, it is recommended to reserve more than 30% of the margin, which is beneficial to the long-term stable operation of the whole machine. The module should be far away from the power electromagnetic, transformer, high-frequency wiring and other parts with large electromagnetic interference.
- 4. The bottom of module should avoid high-frequency digital routing, high-frequency analog routing and power routing. If it has to route the wire on the bottom of module, for example, it is assumed that the module is soldered to the Top Layer, the copper must be spread on the connection part of the top layer and the module, and be close to the digital part of module and routed in the Bottom Layer (all copper is well grounded).
- 5. Assuming that the module is soldered or placed in the Top Layer, it is also wrong to randomly route the Bottom Layer or other layers, which will affect the spurs and receiving sensitivity of the module to some degrees;
- 6. Assuming that there are devices with large electromagnetic interference around the module, which will greatly affect



- the module performance. It is recommended to stay away from the module according to the strength of the interference. If circumstances permit, appropriate isolation and shielding can be done.
- 7. Assuming that there are routings of large electromagnetic interference around the module (high-frequency digital, high-frequency analog, power routings), which will also greatly affect the module performance. It is recommended to stay away from the module according to the strength of the interference. If circumstances permit, appropriate isolation and shielding can be done.
- 8. It is recommended to stay away from the devices whose TTL protocol is the same 433 MHz physical layer.
- 9. The antenna installation structure has a great influence on the module performance. It is necessary to ensure the antenna is exposed and preferably vertically upward. When the module is installed inside of the case, a high-quality antenna extension wire can be used to extend the antenna to the outside of the case.
- 10. The antenna must not be installed inside the metal case, which will cause the transmission distance to be greatly weakened.

4.6 Trouble Shooting

4.6.1 Unsatisfactory Transmission Distance

- 1. When there is a linear communication obstacle, the communication distance will be correspondingly weakened. Temperature, humidity, and co-channel interference will lead to an increase in communication packet loss rate. The performances of ground absorption and reflection of radio waves will be poor, when the module is tested close to the ground.
- 2. Seawater has a strong ability to absorb radio waves, so the test results by seaside are poor.
- 3. The signal attenuation will be very obvious, if there is a metal near the antenna or the module is placed inside of the metal shell.
- 4. The incorrect power register set or the high data rate in an open air may shorten the communication distance. The higher the data rate, the closer the distance.
- 5. The low voltage of the power supply is lower than the recommended value at ambient temperature, and the lower the voltage, the smaller the power is.
- 6. The unmatchable antennas and module or the poor quality of antenna will affect the communication distance.

4.6.2 Vulnerable Module

- Please ensure the supply voltage is between the recommended values. The module will be permanently damaged
 if the voltage exceeds the maximum value. Please ensure the stable power supply and no frequently fluctuated
 voltage.
- 2. Please ensure the anti-static installation and the electrostatic sensitivity of high-frequency devices.
- 3. Due to some humidity sensitive components, please ensure the suitable humidity during installation and application.



If there is no special demand, it is not recommended to use at too high or too low temperature.

4.6.3 High Bit Error Rate

- 1. There are co-channel signal interferences nearby. It is recommended to be away from the interference sources or modify the frequency and channel to avoid interferences.
- 2. The unsatisfactory power supply may also cause garbled. It is necessary to ensure the power supply reliability.
- 3. If the extension wire or feeder wire is of poor quality or too long, the bit error rate will be high.

4.7 Electrostatics Discharge Warnings

The module will be damaged for the discharge of static. RF-star suggest that all modules should follow the 3 precautions below:

- 1. According to the anti-static measures, bare hands are not allowed to touch modules.
- 2. Modules must be placed in anti- static areas.
- Take the anti-static circuitry (when inputting HV or VHF) into consideration in product design.
 Static may result in the degradation in performance of module, even causing the failure.

4.8 Soldering and Reflow Condition

- 1. Heating method: Conventional Convection or IR/convection.
- 2. Solder paste composition: Sn96.5 / Ag3.0 / Cu0.5
- 3. Allowable reflow soldering times: 2 times based on the following reflow soldering profile.
- 4. Temperature profile: Reflow soldering shall be done according to the following temperature profile.
- 5. Peak temperature: 245 °C.

Table 7. Temperature Table of Soldering and Reflow

Profile Feature	Sn-Pb Assembly	Pb-Free Assembly
Solder Paste	C., CO / DL O7	Sn96.5 / Ag3.0 /
Soluei Faste	Sn63 / Pb37	Cu0.5
Min. Preheating Temperature (T _{min})	100 ℃	150 ℃
Max. Preheating Temperature (T _{max})	150 ℃	200 ℃
Preheating Time (T _{min} to T _{max}) (t ₁)	60 s ~ 120 s	60 s ~ 120 s
Average Ascend Rate (T _{max} to T _p)	Max. 3 °C/s	Max. 3 °C/s
Liquid Temperature (T∟)	183 ℃	217 ℃
Time above Liquidus (t∟)	60 s ~ 90 s	30 s ~ 90 s
Peak Temperature (T _P)	220 ℃ ~ 235 ℃	230 ℃ ~250 ℃
Average Descend Rate (Tp to Tmax)	Max. 6 °C/s	Max. 6 ℃/s



Time from 25 ℃ to Peak Temperature (t₂)	Max. 6 minutes	Max. 8 minutes
Time of Soldering Zone (tթ)	20±10 s	20±10 s

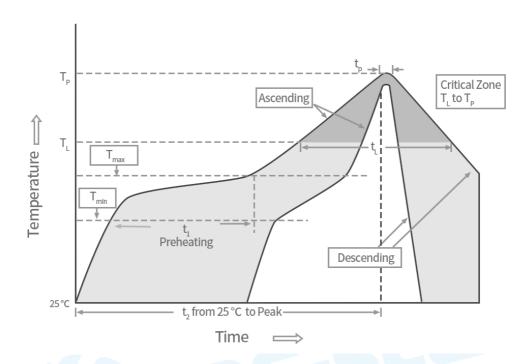


Figure 10. Recommended Reflow for Lead Free Solder

4.9 Optional Packaging



Figure 11. Optional Packaging Mode

Note: Default tray packaging.



5 Certification

5.1 Reach

Reach Certificate No.: C181213010001



Figure 12. SRRC Certificate

5.2 RoHS

Reach Certificate No.: C181213010002



Figure 13. RoHS Certificate



6 Revision History

Date	Version No.	Description	Author
2017.10.19	V1.0	The initial version is released.	Levi
2018.03.12	V1.0	Add commands.	Levi
2018.01.24	V1.0	Add inquiry MAC address function.	Levi
2018.08.02	V1.0	Update module datasheet.	Sunny Li
2020.05.15	V1.0	Add TI CC13XX Sub-1 GHz module list.	Sunny Li

Note:

- 1. The document will be optimized and updated from time to time. Before using this document, please make sure it is the latest version.
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7 Contact Us

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